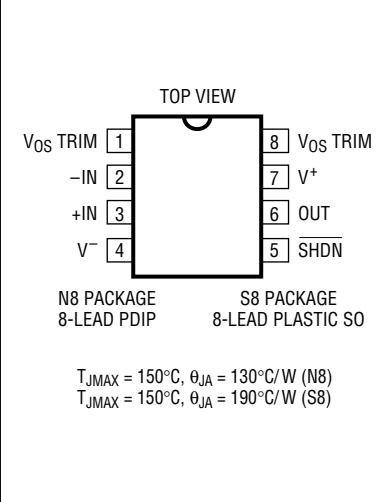


LT1218/LT1219

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	
LT1218/LT1219	$\pm 18\text{V}$
LT1218L/LT1219L	$\pm 8\text{V}$
Input Current	$\pm 15\text{mA}$
Output Short-Circuit Duration (Note 1)	Continuous
Operating Temperature Range	-40°C to 85°C
Specified Temperature Range (Note 3) ...	-40°C to 85°C
Storage Temperature Range	-65°C to 150°C
Junction Temperature	150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LT1218CN8 LT1218CS8 LT1218LCN8 LT1218LCS8 LT1219CN8 LT1219CS8 LT1219LCN8 LT1219LCS8
	S8 PART MARKING
	1218 1219 1218L 1219L

Consult factory for Industrial and Military grades.

ELECTRICAL CHARACTERISTICS

$T_A = 25^{\circ}\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_O = \text{half supply}$, $V_{SHDN} = V^+$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+$ $V_{CM} = V^-$		25 25	90 90	μV μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^-$ to V^+		15	70	μV
I_B	Input Bias Current	$V_{CM} = V^+$ $V_{CM} = V^-$	-70	30 -18	70	nA nA
ΔI_B	Input Bias Current Shift	$V_{CM} = V^-$ to V^+		50	140	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+$ $V_{CM} = V^-$		5 2	18 18	nA nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^-$ to V^+		5	18	nA
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		33		$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density	$f = 1\text{kHz}$		0.09		$\text{pA}/\sqrt{\text{Hz}}$
A_{VOL}	Large-Signal Voltage Gain	$V_S = 5\text{V}$, $V_O = 50\text{mV}$ to 4.8V , $R_L = 10\text{k}$ $V_S = 3\text{V}$, $V_O = 50\text{mV}$ to 2.8V , $R_L = 10\text{k}$	250 200	1000 750		V/mV V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}$, $V_{CM} = V^-$ to V^+ $V_S = 3\text{V}$, $V_{CM} = V^-$ to V^+	97 92	110 106		dB dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.3\text{V}$ to 12V , $V_{CM} = 0\text{V}$, $V_O = 0.5\text{V}$	90	100		dB
V_{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 0.5\text{mA}$ $I_{SINK} = 2.5\text{mA}$		4 45 120	12 90 240	mV mV mV
V_{OH}	Output Voltage Swing HIGH	No Load $I_{SOURCE} = 0.5\text{mA}$ $I_{SOURCE} = 2.5\text{mA}$	$V^+ - 0.012$ $V^+ - 0.130$ $V^+ - 0.400$	$V^+ - 0.003$ $V^+ - 0.065$ $V^+ - 0.210$		V V V
I_{SC}	Short-Circuit Current	$V_S = 5\text{V}$ $V_S = 3\text{V}$	5 4	10 7		mA mA
I_S	Supply Current	$V_S = 5\text{V}$ $V_S = 3\text{V}$		370 370	420 410	μA μA
	Positive Supply Current, SHDN	$V_S = 5\text{V}$, $V_{SHDN} = 0\text{V}$ $V_S = 3\text{V}$, $V_{SHDN} = 0\text{V}$		9 6	30 20	μA μA

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_O = \text{half supply}$, $V_{SHDN} = V^+$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
SR	Slew Rate (LT1218/LT1218L) (LT1219/LT1219L)	$A_V = -1$ $A_V = -1$		0.10 0.05		V/ μs V/ μs
GBW	Gain Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L)	$A_V = 1000$ $A_V = 1000$		0.30 0.15		MHz MHz

$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_O = \text{half supply}$, $V_{SHDN} = V^+$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+$ $V_{CM} = V^-$	● ●	75 75	200 200	μV μV
$V_{OS\ TC}$	Input Offset Drift	(Note 2)	●	1	3	$\mu\text{V}/^\circ\text{C}$
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^- \text{ to } V^+$	●	25	80	μV
I_B	Input Bias Current	$V_{CM} = V^+$ $V_{CM} = V^-$	● ●	30 -18	75	nA nA
ΔI_B	Input Bias Current Shift	$V_{CM} = V^- \text{ to } V^+$	●	50	150	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+$ $V_{CM} = V^-$	● ●	5 3	25 25	nA nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^- \text{ to } V^+$	●	5	25	nA
A_{VOL}	Large-Signal Voltage Gain	$V_S = 5\text{V}$, $V_O = 50\text{mV}$ to 4.8V , $R_L = 10\text{k}$ $V_S = 3\text{V}$, $V_O = 50\text{mV}$ to 2.8V , $R_L = 10\text{k}$	● ●	250 150	1000 750	V/mV V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}$, $V_{CM} = V^- \text{ to } V^+$ $V_S = 3\text{V}$, $V_{CM} = V^- \text{ to } V^+$	● ●	96 91	104 106	dB dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.3\text{V}$ to 12V , $V_{CM} = 0\text{V}$, $V_O = 0.5\text{V}$	●	88	100	dB
V_{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 0.5\text{mA}$ $I_{SINK} = 2.5\text{mA}$	● ● ●	4 45 130	14 100 290	mV mV mV
V_{OH}	Output Voltage Swing HIGH	No Load $I_{SOURCE} = 0.5\text{mA}$ $I_{SOURCE} = 2.5\text{mA}$	● ● ●	$V^+ - 0.014$ $V^+ - 0.150$ $V^+ - 0.480$	$V^+ - 0.004$ $V^+ - 0.075$ $V^+ - 0.240$	V V V
I_{SC}	Short-Circuit Current	$V_S = 5\text{V}$ $V_S = 3\text{V}$	● ●	4 3	7 6	mA mA
I_S	Supply Current	$V_S = 5\text{V}$ $V_S = 3\text{V}$	● ●	370 370	485 475	μA μA
	Positive Supply Current, SHDN	$V_S = 5\text{V}$, $V_{SHDN} = 0\text{V}$ $V_S = 3\text{V}$, $V_{SHDN} = 0\text{V}$	● ●	9 6	36 26	μA μA

$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_O = \text{half supply}$, $V_{SHDN} = V^+$, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$	● ●		400 400	μV μV
$V_{OS\ TC}$	Input Offset Drift	(Note 2)	●	1	4	$\mu\text{V}/^\circ\text{C}$
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$	●	30	105	μV
I_B	Input Bias Current	$V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$	● ●		80	nA nA
ΔI_B	Input Bias Current Shift	$V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$	●		160	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$	● ●		40 40	nA nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$	●		40	nA

ELECTRICAL CHARACTERISTICS

–40°C ≤ T_A ≤ 85°C, V_S = 5V, 0V; V_S = 3V, 0V; V_{CM} = V_O = half supply, V_{SHDN} = V⁺, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
A _{VOL}	Large-Signal Voltage Gain	V _S = 5V, V _O = 50mV to 4.8V, R _L = 10k V _S = 3V, V _O = 50mV to 2.8V, R _L = 10k	● ●	150 100	500 500	V/mV V/mV
CMRR	Common Mode Rejection Ratio	V _S = 5V, V _{CM} = V ⁺ – 0.15 to V [–] + 0.15 V _S = 3V, V _{CM} = V ⁺ – 0.15 to V [–] + 0.15	● ●	93 88	102 100	dB dB
PSRR	Power Supply Rejection Ratio	V _S = 2.3V to 12V, V _{CM} = 0V, V _O = 0.5V	●	86	100	dB
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 0.5mA I _{SINK} = 2.5mA	● ● ●	5 50 130	15 105 300	mV mV mV
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 0.5mA I _{SOURCE} = 2.5mA	● ● ●	V ⁺ – 0.015 V ⁺ – 0.160 V ⁺ – 0.500	V ⁺ – 0.004 V ⁺ – 0.070 V ⁺ – 0.250	mV mV mV
I _{SC}	Short-Circuit Current	V _S = 5V V _S = 3V	● ●	4 3	7 7	mA mA
I _S	Supply Current	V _S = 5V V _S = 3V	● ●	410 400	505 495	μA μA
	Positive Supply Current, SHDN	V _S = 5V, V _{SHDN} = 0V V _S = 3V, V _{SHDN} = 0V	● ●	15 13	50 40	μA μA

LT1218L/LT1219L only; T_A = 25°C, V_S = ±5V, V_{CM} = 0V, V_O = 0V, V_{SHDN} = 5V, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	V _{CM} = V ⁺ V _{CM} = V [–]		35 35	140 140	μV μV
ΔV _{OS}	Input Offset Voltage Shift	V _{CM} = V [–] to V ⁺		20	70	μV
I _B	Input Bias Current	V _{CM} = V ⁺ V _{CM} = V [–]	–70	30 –18	70	nA nA
ΔI _B	Input Bias Current Shift	V _{CM} = V [–] to V ⁺		50	140	nA
I _{OS}	Input Offset Current	V _{CM} = V ⁺ V _{CM} = V [–]		5 2	18 18	nA nA
ΔI _{OS}	Input Offset Current Shift	V _{CM} = V [–] to V ⁺		5	18	nA
A _{VOL}	Large-Signal Voltage Gain	V _O = –4.7V to 4.7V, R _L = 10k V _O = –4.5V to 4.5V, R _L = 2k	500 300	2800 1300		V/mV V/mV
CMRR	Common Mode Rejection Ratio	V _{CM} = V [–] to V ⁺	103	114		dB
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 0.5mA I _{SINK} = 5mA		V [–] + 0.004 V [–] + 0.045 V [–] + 0.180	V [–] + 0.012 V [–] + 0.090 V [–] + 0.525	V V V
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 0.5mA I _{SOURCE} = 5mA	V ⁺ – 0.012 V ⁺ – 0.130 V ⁺ – 0.800	V ⁺ – 0.003 V ⁺ – 0.065 V ⁺ – 0.350		V V V
I _{SC}	Short-Circuit Current		6	12		mA
I _S	Supply Current			400	430	μA
	Positive Supply Current, SHDN	V _{SHDN} = 0V		10	40	μA
SR	Slew Rate (LT1218/LT1218L) (LT1219/LT1219L)	A _V = –1, R _L = Open, V _O = ±3.5V A _V = –1, R _L = Open, V _O = ±3.5V	0.06 0.03	0.10 0.05		V/μs V/μs
GBW	Gain-Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L)	A _V = 1000 A _V = 1000	0.2 0.1	0.30 0.15		MHz MHz

ELECTRICAL CHARACTERISTICS

LT1218L/LT1219L only; $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, $V_S = \pm 5\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{SHDN} = 5\text{V}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+$	●	100	250	μV
		$V_{CM} = V^-$	●	100	250	μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^-$ to V^+	●	30	90	μV
I_B	Input Bias Current	$V_{CM} = V^+$	●	30	75	nA
		$V_{CM} = V^-$	●	-75	-18	nA
ΔI_B	Input Bias Current	$V_{CM} = V^-$ to V^+	●	50	150	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+$	●	5	25	nA
		$V_{CM} = V^-$	●	3	25	nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^-$ to V^+	●	5	20	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = -4.7\text{V}$ to 4.7V , $R_L = 10\text{k}$	●	375	2800	V/mV
		$V_O = -4.5\text{V}$ to 4.5V , $R_L = 2\text{k}$	●	275	1300	V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^-$ to V^+	●	100	110	dB
V_{OL}	Output Voltage Swing LOW	No Load	●	$V^- + 0.004$	$V^- + 0.014$	V
		$I_{SINK} = 0.5\text{mA}$	●	$V^- + 0.045$	$V^- + 0.100$	V
		$I_{SINK} = 5\text{mA}$	●	$V^- + 0.200$	$V^- + 0.580$	V
V_{OH}	Output Voltage Swing HIGH	No Load	●	$V^+ - 0.014$	$V^+ - 0.004$	V
		$I_{SOURCE} = 0.5\text{mA}$	●	$V^+ - 0.150$	$V^+ - 0.075$	V
		$I_{SOURCE} = 5\text{mA}$	●	$V^+ - 0.920$	$V^+ - 0.450$	V
I_{SC}	Short-Circuit Current		●	5	10	mA
I_S	Supply Current		●	400	495	μA
	Positive Supply Current, SHDN	$V_{SHDN} = 0\text{V}$	●	11	54	μA

LT1218L, LT1219L only; $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, $V_S = \pm 5\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{SHDN} = 5\text{V}$, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+ - 0.15$	●	125	500	μV
		$V_{CM} = V^- + 0.15$	●	125	500	μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$	●	35	120	μV
I_B	Input Bias Current	$V_{CM} = V^+ - 0.15$	●		80	nA
		$V_{CM} = V^- + 0.15$	●	-80		nA
ΔI_B	Input Bias Current	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$	●		160	nA
I_{OS}	Input Offset Current Shift	$V_{CM} = V^+ - 0.15$	●		40	nA
		$V_{CM} = V^- + 0.15$	●		40	nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$	●		40	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = -4.7\text{V}$ to 4.7V , $R_L = 10\text{k}$	●	300	2000	V/mV
		$V_O = -4.5\text{V}$ to 4.5V , $R_L = 2\text{k}$	●	200	600	V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$	●	98	109	dB
V_{OL}	Output Voltage Swing LOW	No Load	●	$V^- + 0.005$	$V^- + 0.015$	V
		$I_{SINK} = 0.5\text{mA}$	●	$V^- + 0.050$	$V^- + 0.105$	V
		$I_{SINK} = 2.5\text{mA}$	●	$V^- + 0.200$	$V^- + 0.620$	V
V_{OH}	Output Voltage Swing HIGH	No Load	●	$V^+ - 0.015$	$V^+ - 0.004$	V
		$I_{SOURCE} = 0.5\text{mA}$	●	$V^+ - 0.160$	$V^+ - 0.070$	V
		$I_{SOURCE} = 2.5\text{mA}$	●	$V^+ - 1.000$	$V^+ - 0.400$	V
I_{SC}	Short-Circuit Current		●	5	10	mA
I_S	Supply Current		●	420	525	μA
	Positive Supply Current, SHDN	$V_{SHDN} = 0\text{V}$	●	18	60	μA

ELECTRICAL CHARACTERISTICS

LT1218/LT1219 only; $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{SHDN} = 15\text{V}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+$		85	200	μV
		$V_{CM} = V^-$		85	200	μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^-$ to V^+		30	70	μV
I_B	Input Bias Current	$V_{CM} = V^+$		30	70	nA
		$V_{CM} = V^-$	-70	-18		nA
ΔI_B	Input Bias Current	$V_{CM} = V^-$ to V^+		50	140	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+$		5	18	nA
		$V_{CM} = V^-$		2	18	nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^-$ to V^+		5	18	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$	1000	4000		V/mV
		$V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$	500	2000		V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^-$ to V^+	113	120		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 5\text{V}$ to $\pm 15\text{V}$	100	110		dB
V_{OL}	Output Voltage Swing LOW	No Load		$V^- + 0.004$	$V^- + 0.012$	V
		$I_{SINK} = 0.5\text{mA}$		$V^- + 0.045$	$V^- + 0.090$	V
		$I_{SINK} = 5\text{mA}$		$V^- + 0.270$	$V^- + 0.525$	V
V_{OH}	Output Voltage Swing HIGH	No Load	$V^+ - 0.012$	$V^+ - 0.003$		V
		$I_{SOURCE} = 0.5\text{mA}$	$V^+ - 0.130$	$V^+ - 0.065$		V
		$I_{SOURCE} = 5\text{mA}$	$V^+ - 0.800$	$V^+ - 0.580$		V
I_{SC}	Short-Circuit Current		10	20		mA
I_S	Supply Current			425	550	μA
		Positive Supply Current, SHDN		15	40	μA
SR	Slew Rate (LT1218/LT1218L) (LT1219/LT1219L)	$A_V = -1$		0.10		V/ μs
		$A_V = -1$		0.05		V/ μs
GBW	Gain Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L)	$A_V = 1000$		0.28		MHz
		$A_V = 1000$		0.15		MHz

LT1218/LT1219 only; $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{SHDN} = 15\text{V}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+$	●	120	300	μV
		$V_{CM} = V^-$	●	120	300	μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^-$ to V^+	●	50	105	μV
I_B	Input Bias Current	$V_{CM} = V^+$	●	30	75	nA
		$V_{CM} = V^-$	●	-75	-18	nA
ΔI_B	Input Bias Current	$V_{CM} = V^-$ to V^+	●	50	150	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+$	●	5	25	nA
		$V_{CM} = V^-$	●	3	25	nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^-$ to V^+	●	5	20	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$	●	750	3000	V/mV
		$V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$	●	500	1500	V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^-$ to V^+	●	109	114	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 5\text{V}$ to $\pm 15\text{V}$	●	97	110	dB
V_{OL}	Output Voltage Swing LOW	No Load	●	$V^- + 0.004$	$V^- + 0.014$	V
		$I_{SINK} = 0.5\text{mA}$	●	$V^- + 0.045$	$V^- + 0.100$	V
		$I_{SINK} = 5\text{mA}$	●	$V^- + 0.310$	$V^- + 0.580$	V
V_{OH}	Output Voltage Swing HIGH	No Load	●	$V^+ - 0.014$	$V^+ - 0.003$	V
		$I_{SOURCE} = 0.5\text{mA}$	●	$V^+ - 0.150$	$V^+ - 0.075$	V
		$I_{SOURCE} = 5\text{mA}$	●	$V^+ - 0.920$	$V^+ - 0.700$	V

ELECTRICAL CHARACTERISTICS

LT1218/LT1219 only; $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{SHDN} = 15\text{V}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_{SC}	Short-Circuit Current	●	8	17		mA
I_S	Supply Current	●		450	600	μA
	Positive Supply Current, SHDN	$V_{SHDN} = 0\text{V}$ ●		20	54	μA

LT1218, LT1219 only; $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, $V_S = \pm 15\text{V}$; $V_{CM} = 0\text{V} = V_O$, $V_{SHDN} = 15\text{V}$, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = V^+ - 0.15$ ● $V_{CM} = V^- + 0.15$ ●		150 150	600 600	μV μV
ΔV_{OS}	Input Offset Voltage Shift	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ ●		50	165	μV
I_B	Input Bias Current	$V_{CM} = V^+ - 0.15$ ● $V_{CM} = V^- + 0.15$ ●	-80		80	nA nA
ΔI_B	Input Bias Current	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ ●			160	nA
I_{OS}	Input Offset Current	$V_{CM} = V^+ - 0.15$ ● $V_{CM} = V^- + 0.15$ ●			40 40	nA nA
ΔI_{OS}	Input Offset Current Shift	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ ●			40	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$ ● $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ ●	500 400	3000 1000		V/mV V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ ●	105	114		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ ●	96	110		dB
V_{OL}	Output Voltage Swing LOW	No Load ● $I_{SINK} = 0.5\text{mA}$ ● $I_{SINK} = 2.5\text{mA}$ ●		$V^- + 0.005$ $V^- + 0.050$ $V^- + 0.200$	$V^- + 0.015$ $V^- + 0.105$ $V^- + 0.620$	V V V
V_{OH}	Output Voltage Swing HIGH	No Load ● $I_{SOURCE} = 0.5\text{mA}$ ● $I_{SOURCE} = 2.5\text{mA}$ ●	$V^+ - 0.015$ $V^+ - 0.160$ $V^+ - 1.000$	$V^+ - 0.004$ $V^+ - 0.070$ $V^+ - 0.400$		V V V
I_{SC}	Short-Circuit Current	●	5	14		mA
I_S	Supply Current	●			650	μA
	Positive Supply Current, SHDN	$V_{SHDN} = 0\text{V}$ ●			60	μA

The ● denotes specifications which apply over the full operating temperature range.

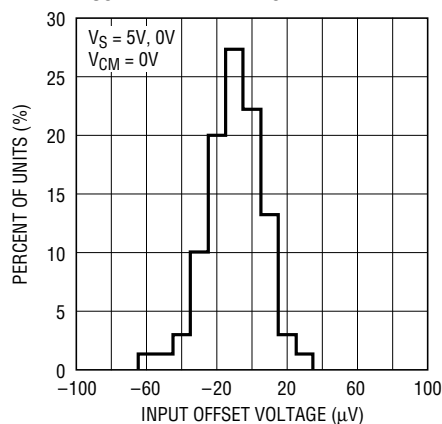
Note 1: A heat sink may be required to keep the junction temperature below the Absolute Maximum Rating when the output is shorted indefinitely.

Note 2: This parameter is not 100% tested.

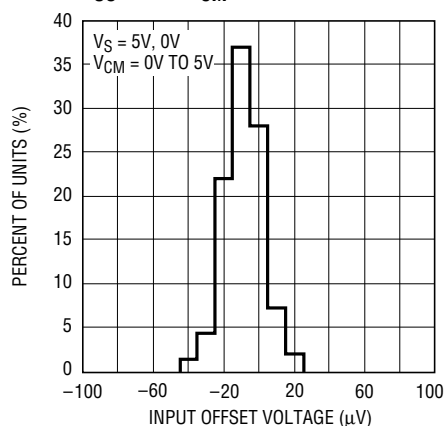
Note 3: The LT1218/LT1219 are designed, characterized and expected to meet these extended temperature limits, but are not tested at -40°C and 85°C . Guaranteed I grade part are available: consult factory.

TYPICAL PERFORMANCE CHARACTERISTICS

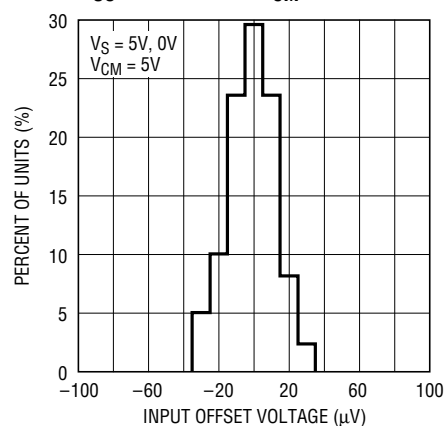
V_{OS} Distribution, $V_{CM} = 0V$



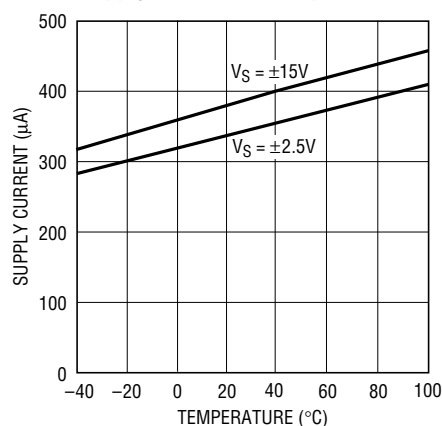
V_{OS} Shift, $V_{CM} = 0V$ to $5V$



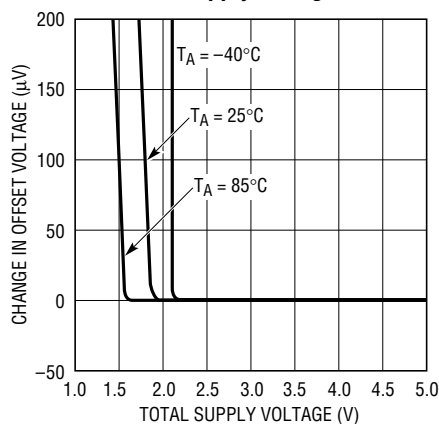
V_{OS} Distribution, $V_{CM} = 5V$



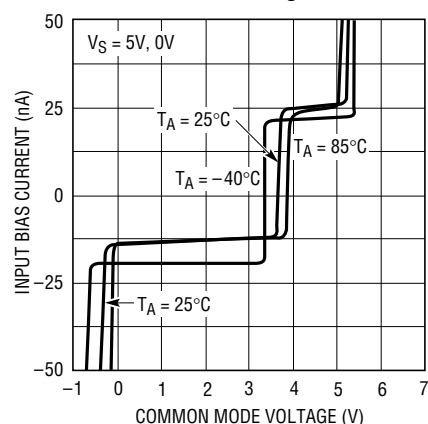
Supply Current vs Temperature



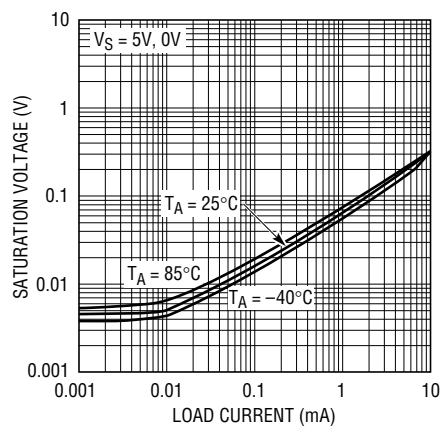
Minimum Supply Voltage



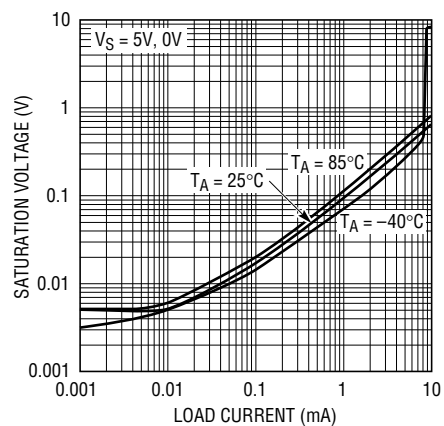
Input Bias Current vs Common Mode Voltage



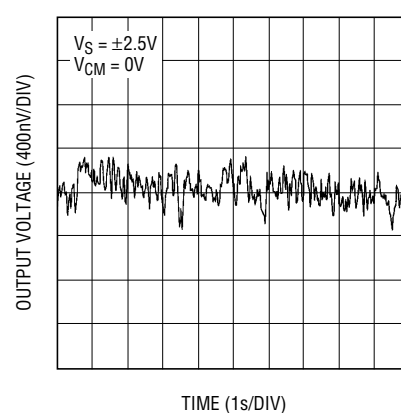
Output Saturation Voltage vs Load Current (Output Low)



Output Saturation Voltage vs Load Current (Output High)

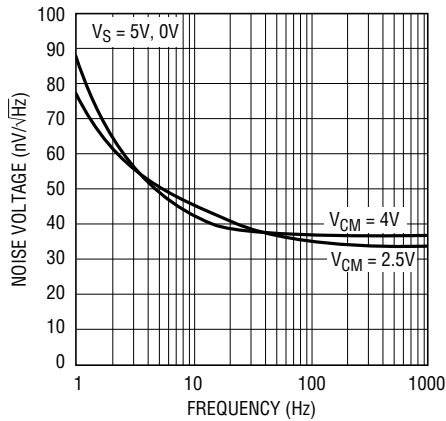


0.1Hz to 10Hz Output Voltage Noise



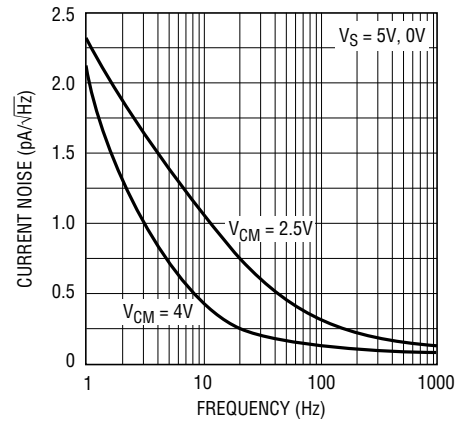
TYPICAL PERFORMANCE CHARACTERISTICS

Noise Voltage Spectrum



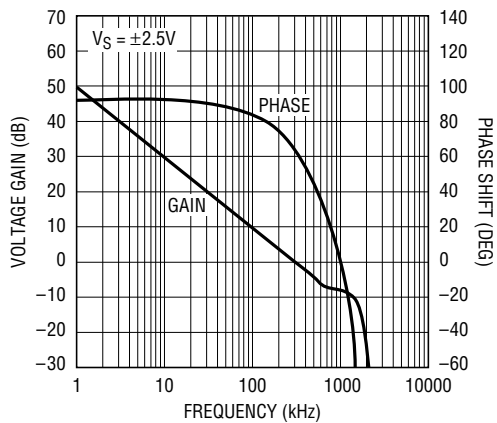
LT1218/19 • TPC10

Noise Current Spectrum



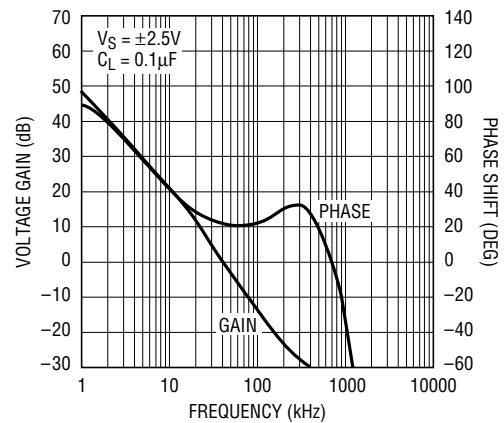
LT1218/19 • TPC11

LT1218 Gain and Phase Shift vs Frequency



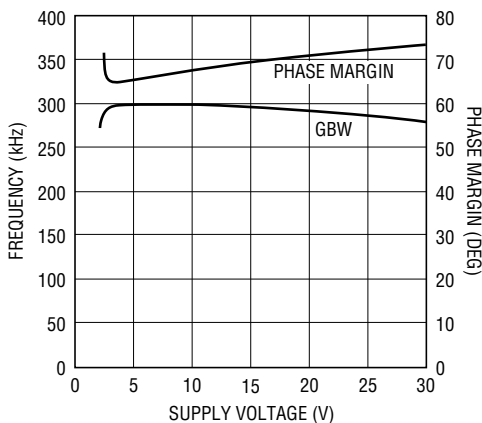
LT1218/19 • TPC12

LT1219 Gain and Phase Shift vs Frequency



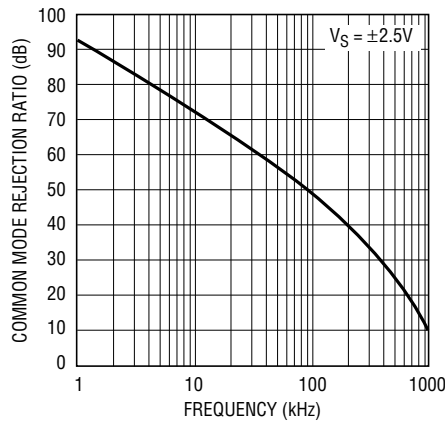
LT1218/19 • TPC13

LT1218 Gain Bandwidth and Phase Margin vs Supply Voltage



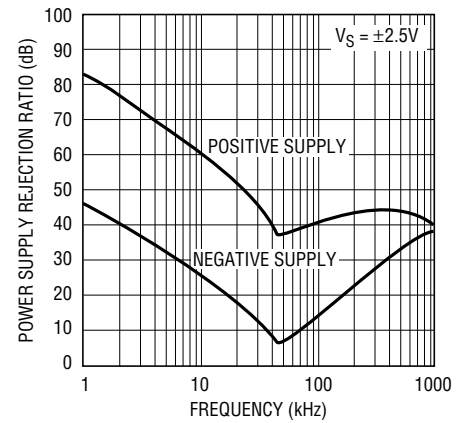
LT1218/19 • TPC

LT1218 Common Mode Rejection Ratio vs Frequency



LT1218/19 • TPC15

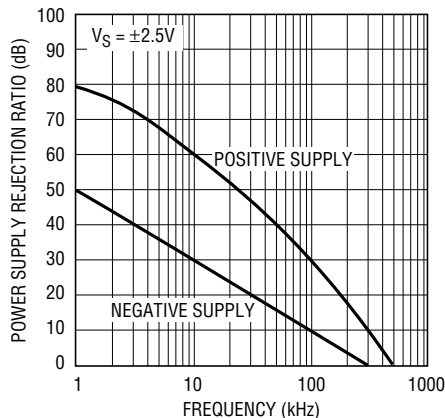
LT1219 Power Supply Rejection Ratio vs Frequency



LT1218/19 • TPC16

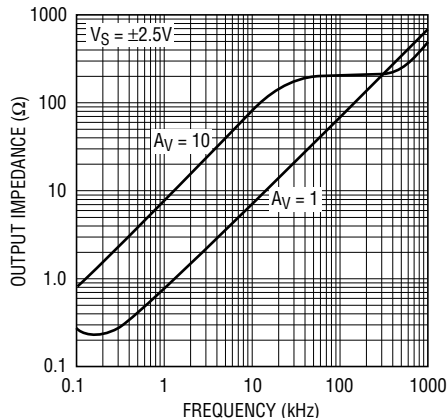
TYPICAL PERFORMANCE CHARACTERISTICS

LT1218 Power Supply Rejection Ratio vs Frequency



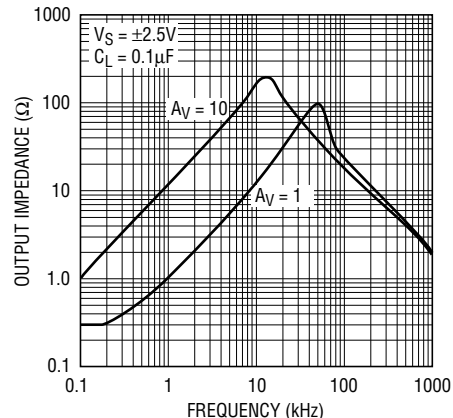
LT1218/19 • TPC17

LT1218 Closed Loop Output Impedance vs Frequency



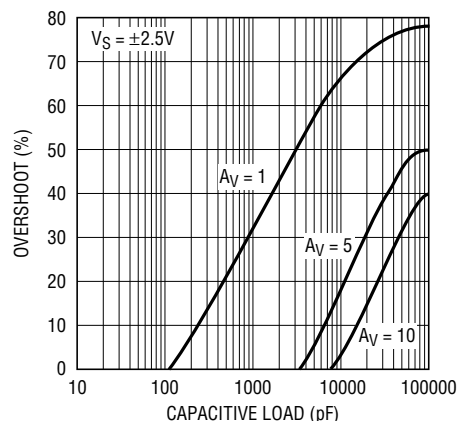
LT1218/19 • TPC18

LT1219 Closed Loop Output Impedance vs Frequency



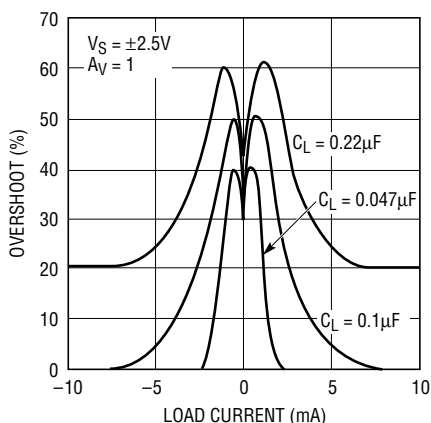
LT1218/19 • TPC19

LT1218 Capacitive Load Handling



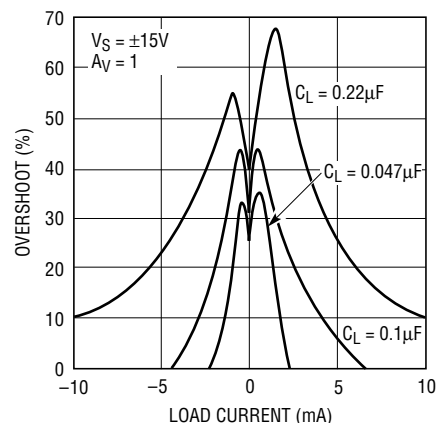
LT1218/19 • TPC20

LT1219 Overshoot vs Load Current, $V_S = \pm 2.5V$



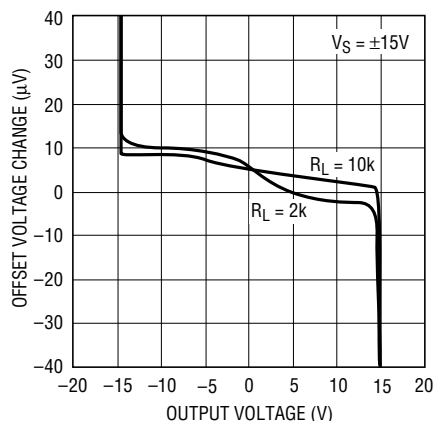
LT1218/19 • TPC21

LT1219 Overshoot vs Load Current, $V_S = \pm 15V$



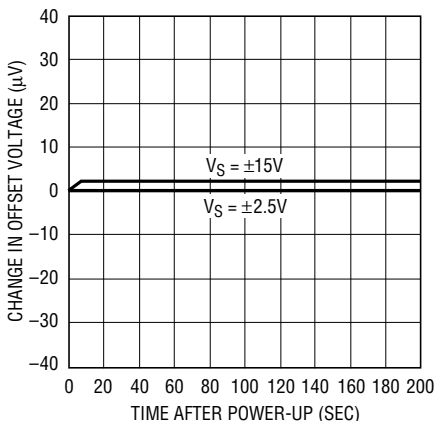
LT1218/19 • TPC22

Open-Loop Gain, $V_S = \pm 15V$



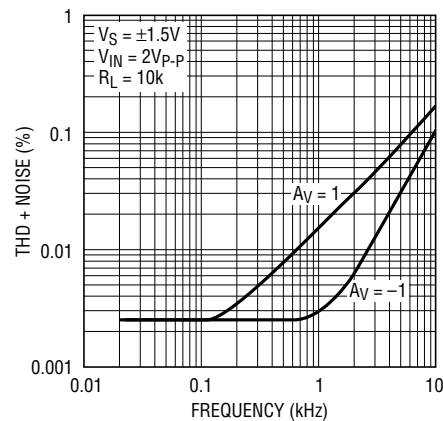
LT1218/19 • TPC23

Input Offset Drift vs Time



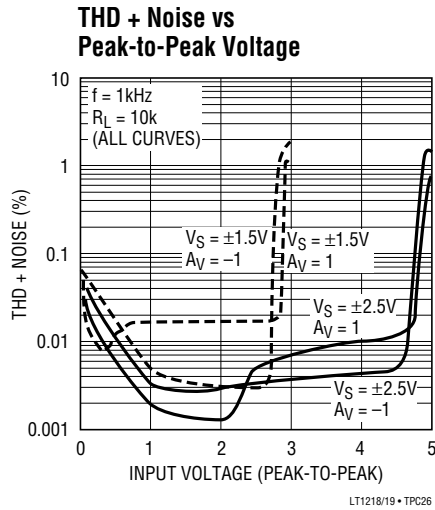
LT1218/19 • TPC24

THD + Noise vs Frequency

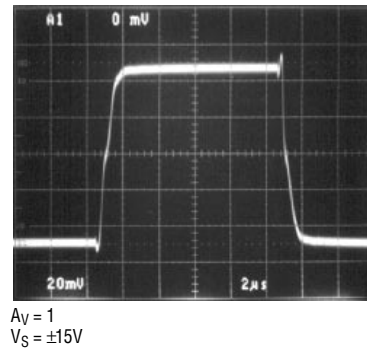


LT1218/19 • TPC25

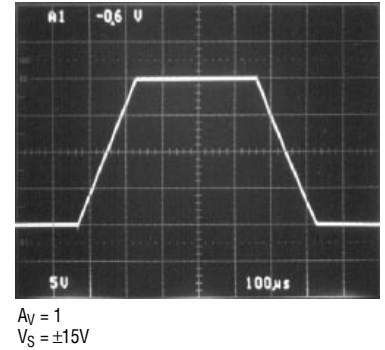
TYPICAL PERFORMANCE CHARACTERISTICS



Small-Signal Response
 $V_S = \pm 15\text{V}$



Large-Signal Response
 $V_S = \pm 15\text{V}$



APPLICATIONS INFORMATION

Rail-to-Rail Operation

The LT1218/LT1219 differ from conventional op amps in the design of both the input and output stages. Figure 1 shows a simplified schematic of the amplifier. The input stage consists of two differential amplifiers, a PNP stage

Q1/Q2 and an NPN stage Q3/Q4, which are active over different portions of the input common mode range. Lateral devices are used in both input stages, eliminating the need for clamps across the input pins. Each input stage is trimmed for offset voltage. A complementary output configuration (Q23 through Q26) is employed to create an

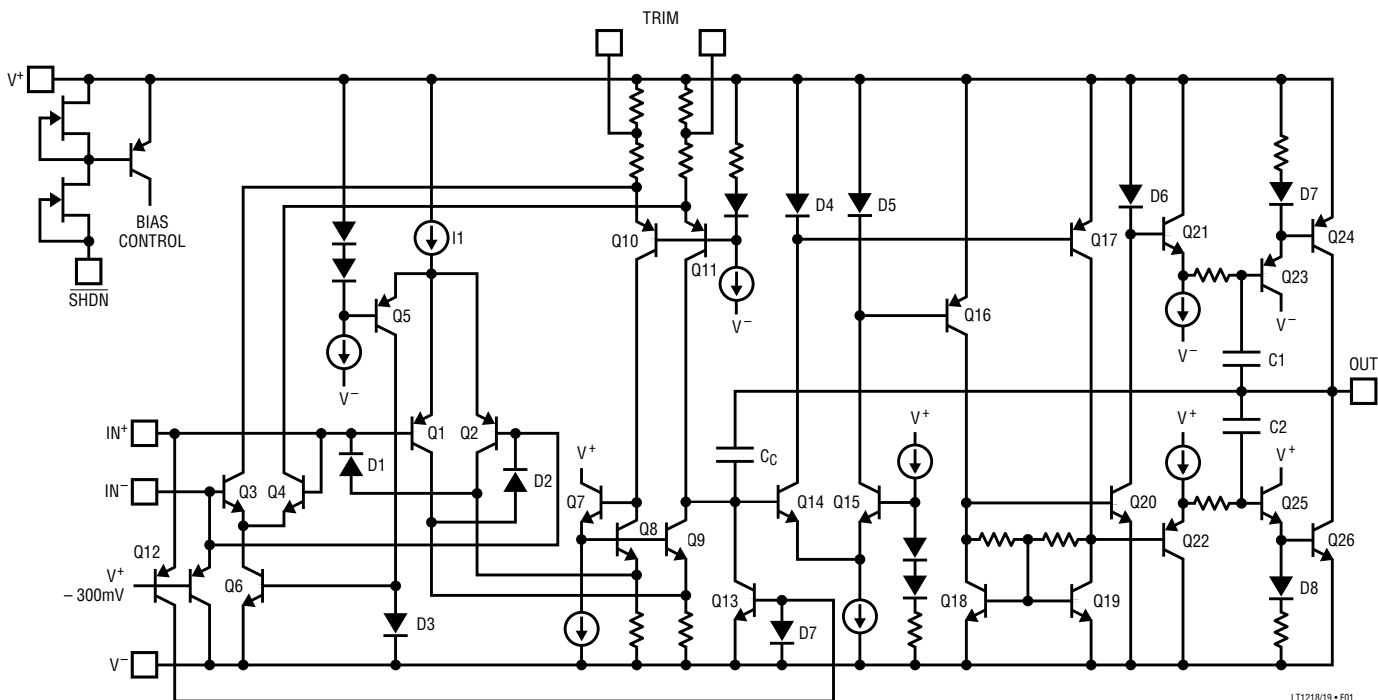


Figure 1. LT1218 Simplified Schematic Diagram

APPLICATIONS INFORMATION

output stage with rail-to-rail swing. The amplifier is fabricated on Linear Technology's proprietary complementary bipolar process, which ensures very similar DC and AC characteristics for the output devices Q24 and Q26.

A simple comparator Q5 steers current from current source I_1 between the two input stages. When the input common mode voltage V_{CM} is near the negative supply, Q5 is reverse biased, and I_1 becomes the tail current for the PNP differential pair Q1/Q2. At the other extreme, when V_{CM} is within about 1.3V from the positive supply, Q5 diverts I_1 to the current mirror D3/Q6, which furnishes the tail current for the NPN differential pair Q3/Q4.

The collector currents of the two input pairs are combined in the second stage, consisting of Q7 through Q11. Most of the voltage gain in the amplifier is contained in this stage. Differential amplifier Q14/Q15 buffers the output of the second stage, converting the output voltage to differential currents. The differential currents pass through current mirrors D4/Q17 and D5/Q16, and are converted to differential voltages by Q18 and Q19. These voltages are also buffered and applied to the output Darlington pairs Q23/Q24 and Q25/Q26. Capacitors C1 and C2 form local feedback loops around the output devices, lowering the output impedance at high frequencies.

Input Offset Voltage

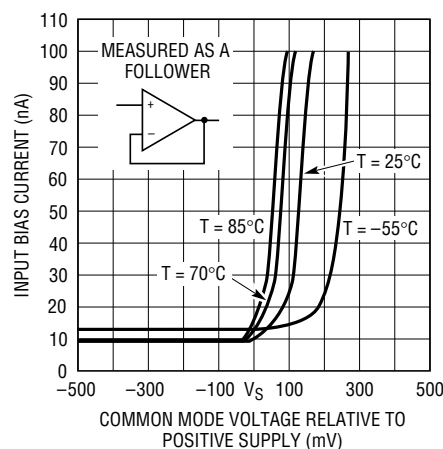
Since the amplifier has two input stages, the input offset voltage changes depending upon which stage is active. The input offsets are random, but bounded voltages. When the amplifier switches between stages, offset voltages may go up, down or remain flat; but will not exceed the guaranteed limits. This behavior is illustrated in three distribution plots of input offset voltage in the Typical Performance Characteristics section.

Overdrive Protection

Two circuits prevent the output from reversing polarity when the input voltage exceeds the common mode range. When the noninverting input exceeds the positive supply by approximately 300mV, the clamp transistor Q12 (Fig-

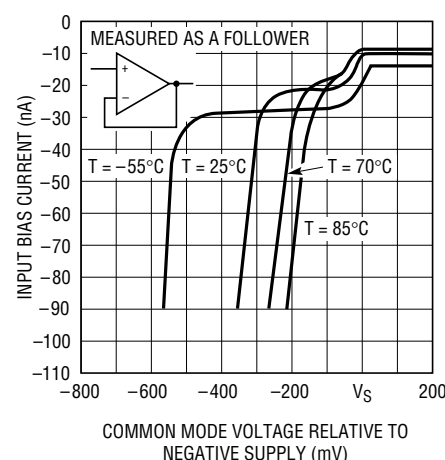
ure 1) turns on, pulling the output of the second stage low, which forces the output high. For input below the negative supply, diodes D1 and D2 turn on, overcoming the saturation of the input pair Q1/Q2.

When overdriven, the amplifier draws input current that exceeds the normal input bias current. Figures 2 and 3 show typical input current as a function of input voltage. The input current must be less than 10mA for the phase reversal protection to work properly. When the amplifier is severely overdriven, an external resistor should be used to limit the overdrive current.



LT1218/19 • F02

Figure 2. Input Bias Current vs Common Mode Voltage



LT1218/19 • F03

Figure 3. Input Bias Current vs Common Mode Voltage

APPLICATIONS INFORMATION

Shutdown

The biasing of the LT1218/LT1219 is controlled by the $\overline{\text{SHDN}}$ pin. When the $\overline{\text{SHDN}}$ pin is low, the part is shut down. In the shutdown mode, the output looks like a 40pF capacitor and the supply current is less than 30 μ A. The $\overline{\text{SHDN}}$ pin is referenced to the positive supply through an internal bias circuit (see Figure 1). The $\overline{\text{SHDN}}$ pin current with the pin low is typically 3 μ A.

The switching time between the shutdown and active states is about 20 μ s, however, the total time to settle will be greater by the slew time of the amplifier. For example, if the DC voltage at the amplifier output is 0V in shutdown and -2V in the active mode, an additional 20 μ s is required. Figures 4a and 4b show the switching waveforms for a sinusoidal and a -2V DC input to the LT1218.

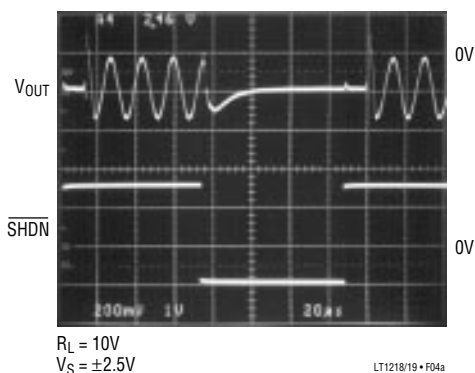


Figure 4a

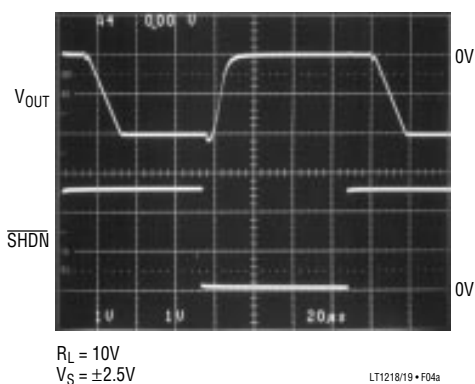


Figure 4b

The $\overline{\text{SHDN}}$ pin can be driven directly from CMOS logic if the logic and the LT1218/LT1219 are operated from the same supplies. For higher supply operation, an interface is required. An easy way to interface between supplies is to use open-drain logic, an example is shown in Figure 5. Because the $\overline{\text{SHDN}}$ pin is referenced to the positive supply, the logic used should have a breakdown voltage greater than the positive supply.

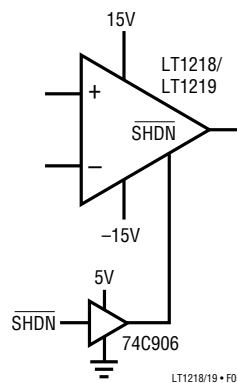


Figure 5. Shutdown Interface

Trim Pins

Trim pins are provided for compatibility with other single op amps. Input offset voltage can be adjusted over a ± 2.3 mV range with a 10k potentiometer.

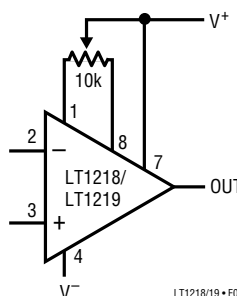


Figure 6. Optional Offset Nulling

Improved Supply Rejection in the LT1219

The LT1219 is a variation of the LT1218 offering greater supply rejection and lower high frequency output impedance. The LT1219 requires a 0.1 μ F load capacitance for

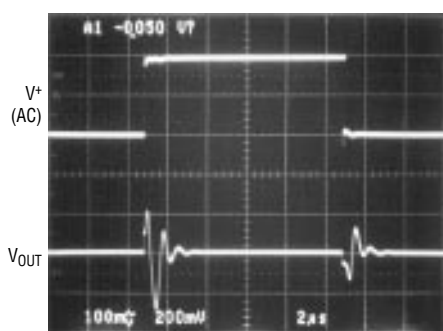
APPLICATIONS INFORMATION

compensation. The output capacitance forms a filter, which reduces pickup from the supply and lowers the output impedance. This additional filtering is helpful in mixed analog/digital systems with common supplies or systems employing switching supplies. Filtering also reduces high frequency noise, which may be beneficial when driving A/D converters.

Figures 7a and 7b show the outputs of the LT1218/LT1219 perturbed by a 200mV_{P-P} 50kHz square wave added to the

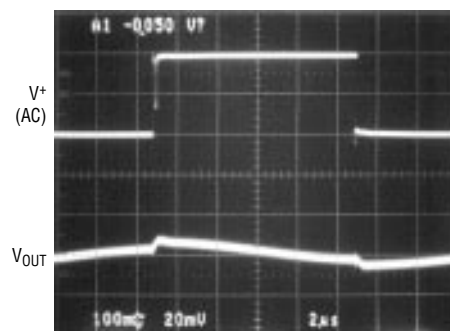
positive supply. The LT1219 power supply rejection is about ten times greater than that of the LT1218 at 50kHz. Note the 5-to-1 scale change in the output voltage traces.

The tolerance of the external compensation capacitor is not critical. The plots of Overshoot vs Load Current in the Typical Performance Characteristics section illustrate the effect of a capacitive load.



LT1218/19 • F07a

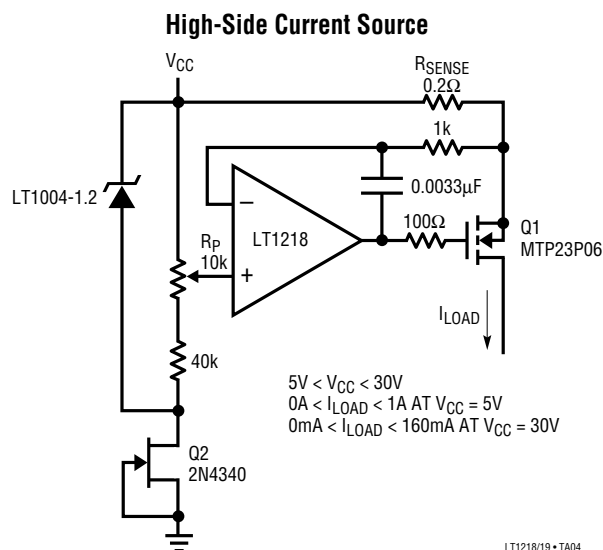
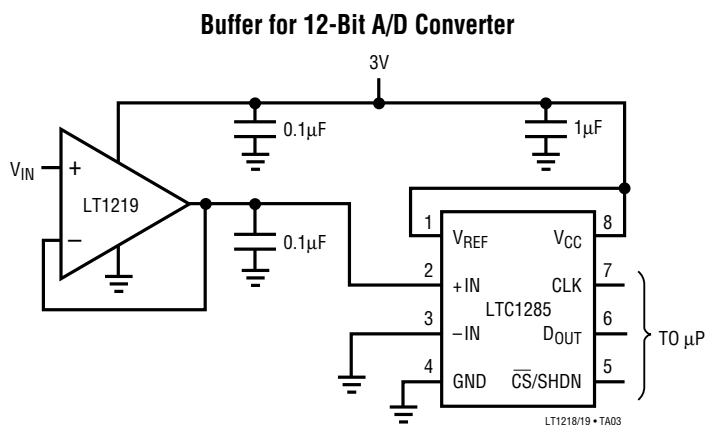
Figure 7a. LT1218 Power Supply Rejection Test



LT1218/19 • F07b

Figure 7b. LT1219 Power Supply Rejection Test

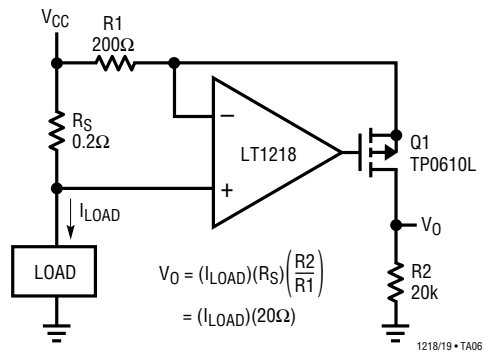
TYPICAL APPLICATIONS



LT1218/19 • TA04

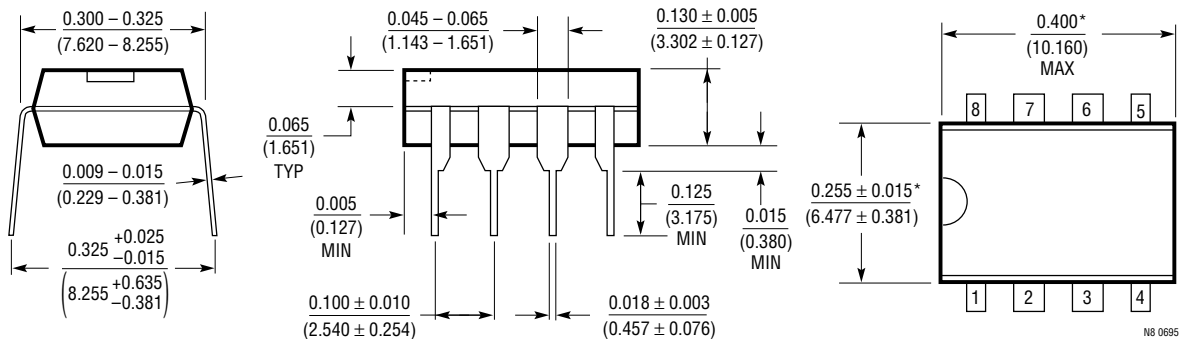
TYPICAL APPLICATIONS

Positive Supply Current Sense

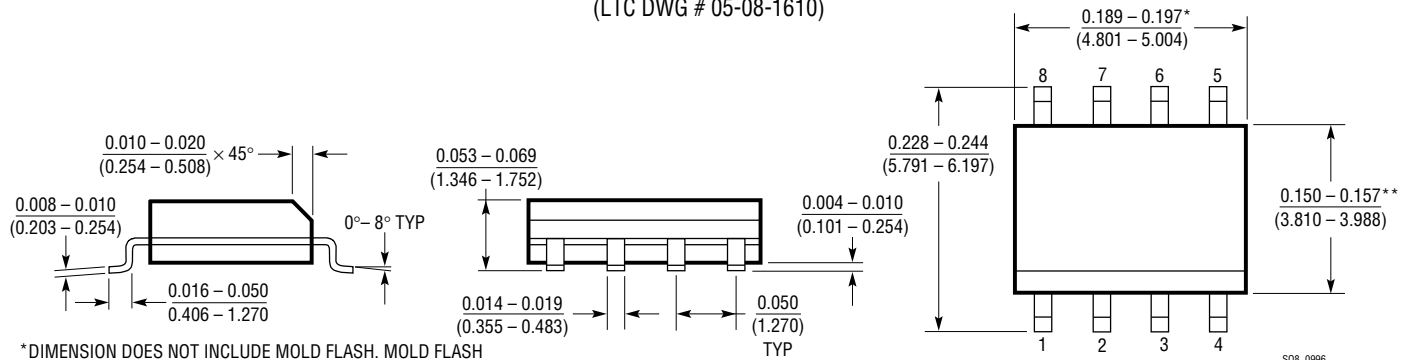


PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

N8 Package 8-Lead PDIP (Narrow 0.300) (LTC DWG # 05-08-1510)

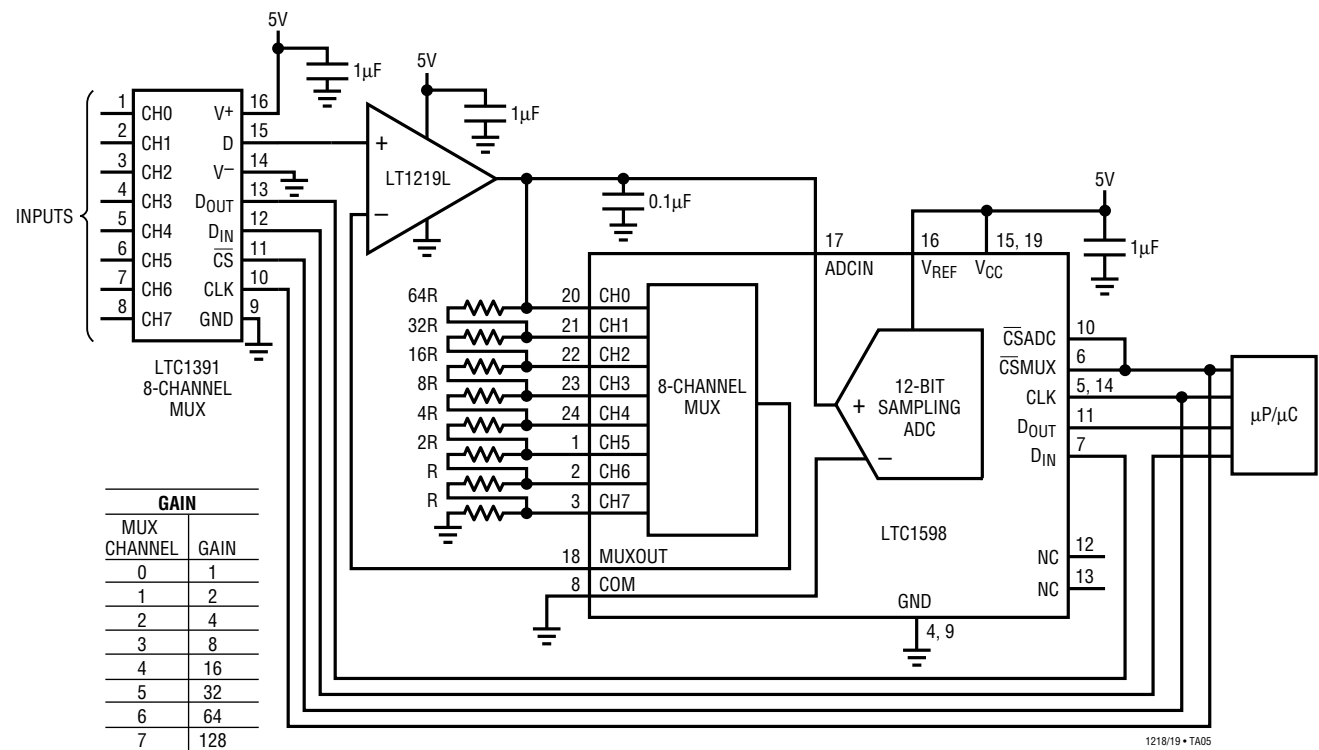


S8 Package 8-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)



TYPICAL APPLICATION

8-Channel, 12-Bit Data Acquisition System with Programmable Gain



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC®1152	Rail-to-Rail Input and Output, Zero-Drift Op Amp	High DC Accuracy, 10μV V _{OS(MAX)} , 100nV/°C Drift, 0.7MHz GBW, 0.5V/μs Slew Rate, Maximum Supply Current 3mA
LT1366/LT1367	Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps	475μV V _{OS(MAX)} , 400kHz GBW, 0.13V/μs Slew Rate, Maximum Supply Current 520μA per Op Amp
LT1466/LT1467	Dual/Quad Micropower, Rail-to-Rail Input and Output Op Amps	Maximum Supply Current 75μA per Op Amp, 390μV V _{OS(MAX)} , 120kHz Gain Bandwidth